

TOSHIBA LASER DAIODE

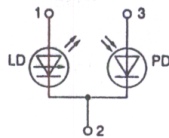
TOLD9462MD

InGaAlP LD

Light Source for DVD Application

- Lasing Wavelength : $\lambda_p = 650\text{nm}$ (typ.)
- Optical Output Power : $P_o = 7\text{mW}$
- Operation Case Temperature : $T_c = -10 \sim 70^\circ\text{C}$

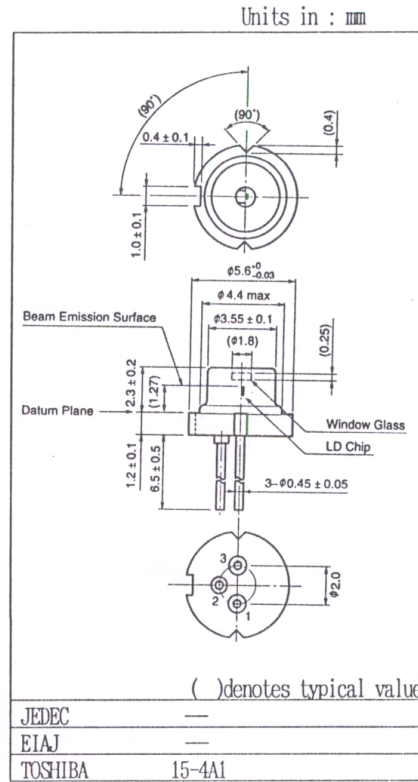
• PIN CONNECTION



1. LASER DIODE ANODE
2. LASER DIODE CATHODE
PHOTODIODE CATHODE
3. PHOTODIODE ANODE

Maximum Ratings ($T_c = 25^\circ\text{C}$)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|----------------------------|-------------|----------|------------------|
| Optical Output Power (CW) | P_o | 7 | mW |
| LD Reverse Voltage | $V_{R(LD)}$ | 2 | V |
| PD Reverse Voltage | $V_{R(PD)}$ | 3.0 | V |
| Operation Case Temperature | T_c | -10 ~ 70 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -40 ~ 85 | $^\circ\text{C}$ |



Optical-Electrical Characteristics ($T_c = 25^\circ\text{C}$)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------------|------------------|------------------------------------|------|------|------|----------|
| Threshold Current | I_{th} | CW Operation | — | 23 | 40 | mA |
| Operation Current | I_{op} | $P_o = 5\text{mW}$ | — | 30 | 45 | mA |
| Operation Voltage | V_{op} | $P_o = 5\text{mW}$ | — | 2.2 | 2.5 | V |
| Lasing Wavelength | λ_p | $P_o = 5\text{mW}$ | 640 | 650 | 660 | nm |
| Beam Divergence | $\theta_{ }$ | $P_o = 5\text{mW}$ | 5 | 8 | 11 | $^\circ$ |
| | θ_{\perp} | $P_o = 5\text{mW}$ | 24 | 28 | 32 | $^\circ$ |
| Monitor Current | I_m | $P_o = 5\text{mW}$ | 0.07 | 0.18 | 0.35 | mA |
| PD Dark Current | $I_{D(PD)}$ | $V_R = 5\text{V}$ | — | — | 100 | nA |
| PD Total Capacitance | $C_T(PD)$ | $V_R = 5\text{V}, f = 1\text{MHz}$ | — | — | 20 | pF |

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PRECAUTIONS:

1. Be careful never to exceed, even momentarily, the maximum ratings. The laser diode is damaged by spike current which can be generated when switching the power ON or OFF. Before activating laser diodes, check the transient state of the power supply to ensure that it will not cause the laser diode to exceed the maximum ratings.
2. Effective heat sinking should be performed, because temperature rise causes decrease of optical output power. Use a thermal radiator to reduce the temperature rise.
3. Prevent electrostatic discharge and electric spike which may damage the laser diode. The following precautions should be taken when using a laser diode.
 1. Set the electrical potential of the work bench to be the same as that of the power supply ground line.
 2. Soldering irons and the operator's body should be grounded.
 3. Do not operate equipment which may generate high frequency surge energy near the laser diode.
4. Do not apply excessive stress between the package and the leads, because it deteriorates hermeticity. If the leads are formed, soldering should be performed after lead forming.
Soldering temperature: 260°C MAX Soldering time: 5 sec MAX
(soldering portion of leads: up to 2mm from the body of the device)
5. Take care not to touch the window glass. Contamination and scratches on the window glass surface will result in decreased optical output power and distorted far-field patterns.
6. Do not look at the laser beam directly or through lenses when the laser diode is activated. The laser beam emitted by laser diode is harmful if aimed directly into human eye.
7. Toshiba Visible Laser Diodes are available in two types of carton to which the following warning labels are attached :-
 1. Envelope Package(1 piece): warning labels are included on the reverse side of the individual envelope
 2. Tray Package(200 pieces): warning labels are attached to the top of the external carton that contains the tray.
 *due to the small size of the laser diodes, the warning labels are placed on the laser diode packaging and not on the individual laser diodes.

